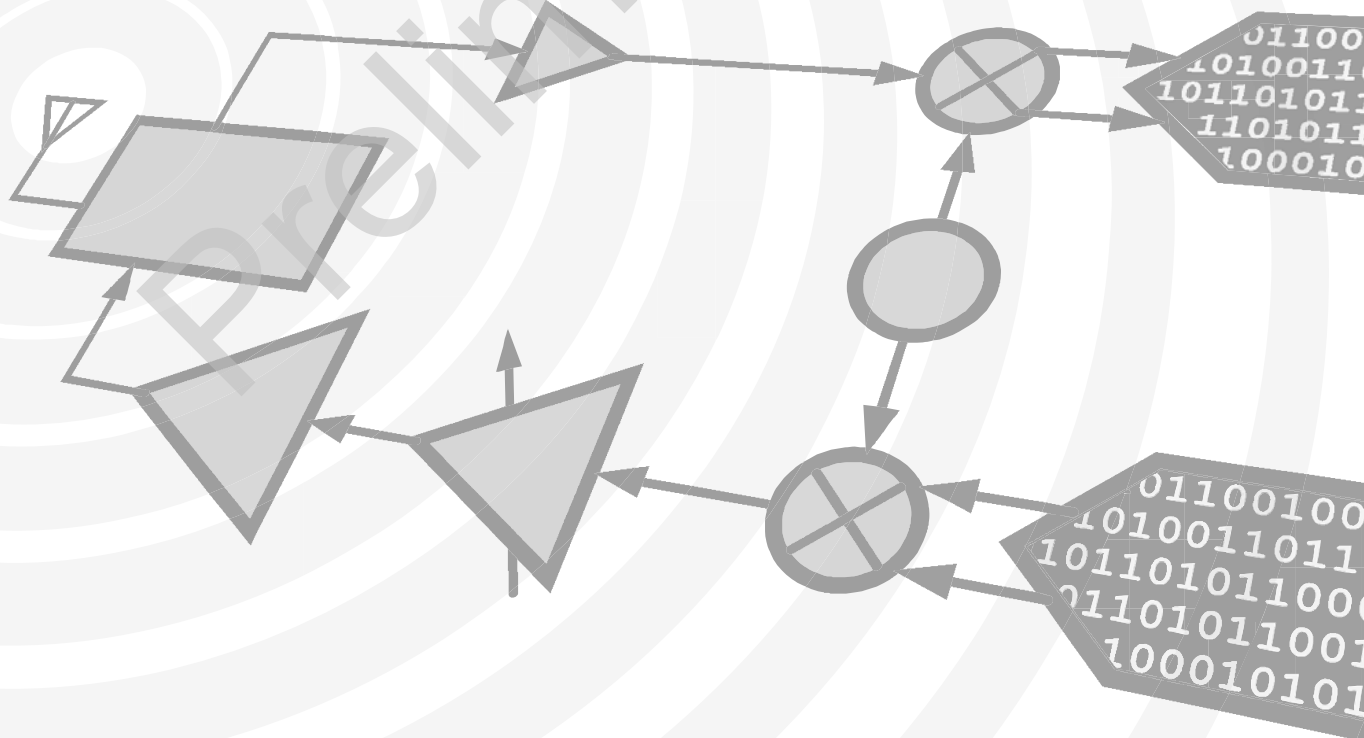


Analog Devices Welcomes Hittite Microwave Corporation



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Preliminary

1.0 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 40 GHz

Typical Applications

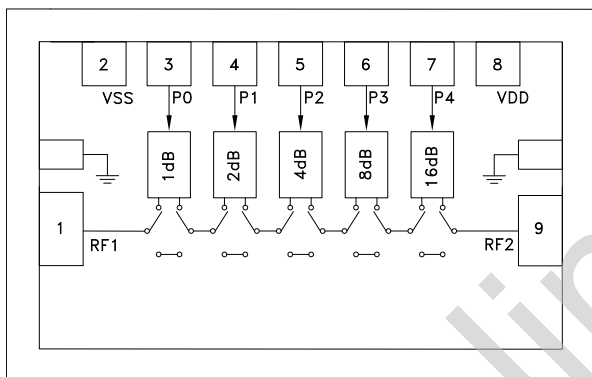
The HMC939A is ideal for:

- Fiber Optics & Broadband Telecom
- Microwave Radio & VSAT
- Military Radios, Radar & ECM
- Space Applications

Features

- 1.0 dB LSB Steps to 31 dB
- Single Positive Control Line Per Bit
- ± 1.0 dB Typical Bit Error
- High Input IP3: +43 dBm
- Die Size: 2.29 x 0.95 x 0.1 mm

Functional Diagram



General Description

The HMC939A die is a broadband 5-bit GaAs IC digital attenuator MMIC chip. Covering 0.1 to 40 GHz, the insertion loss is less than 5 dB typical. The attenuator bit values are 1.0 (LSB), 2, 4, 8, 16 for a total attenuation of 31 dB. Attenuation accuracy is excellent at less than ± 1.0 dB typical step error with an IIP3 of +43 dBm. Five control voltage inputs, toggled between +5V and 0V, are used to select each attenuation state.

Electrical Specifications, $T_A = +25^\circ \text{C}$, With $V_{dd} = +5\text{V}$, $V_{ss} = -5\text{V}$ & $V_{CTL} = 0/ +5\text{V}$

Parameter	Frequency (GHz)	Min.	Typ.	Max.	Units
Insertion Loss	0.1 - 18 GHz		3.5	5.0	dB
	18 - 40 GHz		6.0	7.5	dB
Attenuation Range	0.1 - 40 GHz		31		dB
Return Loss (RF1 & RF2, All Atten. States)	0.1 - 40 GHz		12		dB
Attenuation Accuracy: (Referenced to Insertion Loss)	1.0 - 15 dB States	$\pm 0.5 + 5\%$ of Atten. Setting Max			dB
	16 - 31 dB States				dB
Input Power for 0.1 dB Compression	0.1 - 0.5 GHz		20		dBm
	0.5 - 40.0 GHz		25		dBm
Input Third Order Intercept Point (Two-Tone Input Power = 0 dBm Each Tone)	0.1 - 0.5 GHz		40		dBm
	0.5 - 40.0 GHz		43		dBm
Switching Characteristics	0.1 - 40 GHz		60		ns
			90		ns
I _{dd}	0.1 - 40 GHz	3	5	7	mA
I _{ss}	0.1 - 40 GHz	-4	-6	-8	mA

1.0 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 40 GHz

Bias Voltages & Currents

Vdd	+5V @ 5 mA
Vss	-5V @ 6 mA

Control Voltage

State	Bias Condition
Low	0 to 0.8V @ 1 μ A
High	2 to 5V @ 1 μ A

Absolute Maximum Ratings

RF Input Power (0.5 to 40 GHz)	+25 dBm
Control Voltage (P0 to P4)	Vdd + 0.5V
Vdd	+7 Vdc
Vss	-7 Vdc
Channel Temperature	150 °C
Thermal Resistance (channel to die bottom)	144 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C

Truth Table

Control Voltage Input					Attenuation State RF1 - RF2
P4 16 dB	P3 8 dB	P2 4 dB	P1 2 dB	P0 1 dB	
High	High	High	High	High	Reference I.L.
High	High	High	High	Low	1 dB
High	High	High	Low	High	2 dB
High	High	Low	High	High	4 dB
High	Low	High	High	High	8 dB
Low	High	High	High	High	16 dB
Low	Low	Low	Low	Low	31 dB

Any Combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing

